

Specification Sheet

DSP Silicon Wafer P Type

(2", Boron Doped)

Stock No: NS6130-10-1175, CAS: 7440-21-3

Product	:	DSP Silicon Wafer P Type
Stock No	:	NS6130-10-1175
CAS	:	7440-21-3
Diameter	:	02" (50.8mm)
Thickness	:	450 μ m
Crystal Orientation	:	< 100>
Type	:	P
Resistivity	:	1-10ohm-cm
Surface	:	Double Side Polished
Doping	:	Boron
Main Inspect Verifier	:	Manager QC

Note: Product Specification are subject to amendment and may change over time

Characterization of DSP Silicon Wafer P Type



DSP Silicon Wafer P Type



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